## NSN 5961-00-238-9352

**Fiig:** A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-238-9352 **Inclosure Material:** Metal **Overall Length:** 1.080 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Gate **Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.057 inches Thread Size: 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 700.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited **Current Rating Per Characteristic:** 110.00 amperes forward current, average of standard range **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 10001-2805536 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No